

查询"MP4303_07"快速响应 TOSHIBA Power Transistor Module Silicon NPN Epitaxial Type
(Four Darlington Power Transistors in One)

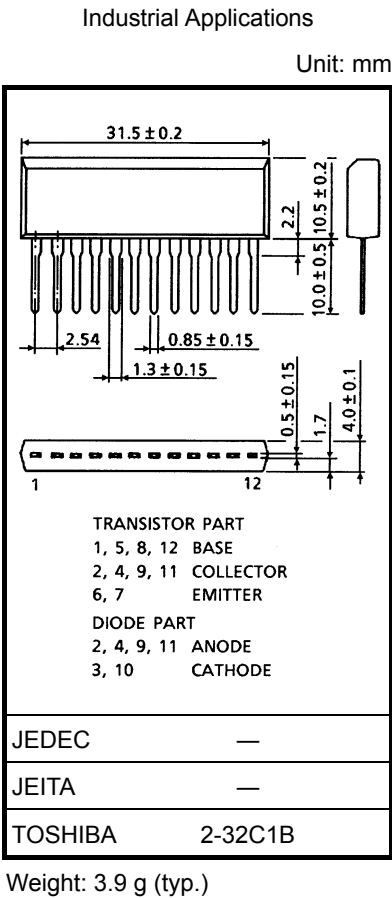
MP4303

High Power Switching Applications
Hammer Drive, Pulse Motor Drive and Inductive Load Switching

- Small package by full molding (SIP 12 pins)
- High collector power dissipation (4-device operation)
: $P_T = 4.4\text{ W}$ ($T_a = 25^\circ\text{C}$)
- High collector current: I_C (DC) = 2 A (max)
- High DC current gain: $h_{FE} = 2000$ (min) ($V_{CE} = 2\text{ V}$, $I_C = 1\text{ A}$)

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

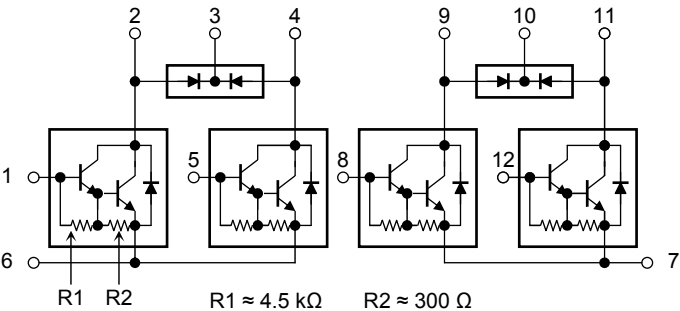
Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	120	V
Collector-emitter voltage		V_{CEO}	100	V
Emitter-base voltage		V_{EBO}	6	V
Collector current	DC	I_C	2	A
	Pulse	I_{CP}	4	
Continuous base current		I_B	0.5	A
Collector power dissipation (1 -evice operation)		P_C	2.2	W
Collector power dissipation (4-device operation)		P_T	4.4	W
Junction temperature		T_j	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	-55 to 150	$^\circ\text{C}$



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

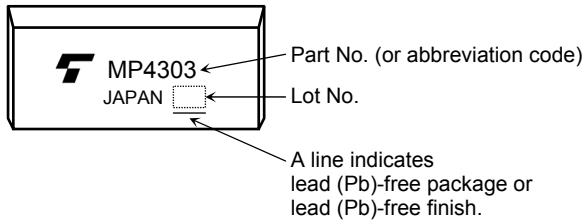
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Array Configuration



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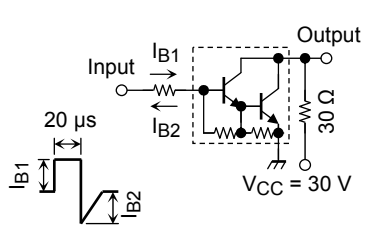
Marking



Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance from junction to ambient (4-device operation, Ta = 25°C)	$\Sigma R_{th(j-a)}$	28.4	°C/W
Maximum lead temperature for soldering purposes (3.2 mm from case for 10 s)	T _L	260	°C

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = 120 V, I _E = 0 A	—	—	10	μA
Collector cut-off current		I _{CEO}	V _{CE} = 100 V, I _B = 0 A	—	—	10	μA
Emitter cut-off current		I _{EBO}	V _{EB} = 6 V, I _C = 0 A	0.5	—	2.5	mA
Collector-base breakdown voltage		V _{(BR) CBO}	I _C = 1 mA, I _E = 0 A	120	—	—	V
Collector-emitter breakdown voltage		V _{(BR) CEO}	I _C = 10 mA, I _B = 0 A	100	—	—	V
DC current gain		h _{FE} (1)	V _{CE} = 2 V, I _C = 1 A	2000	—	15000	—
		h _{FE} (2)	V _{CE} = 2 V, I _C = 2 A	1000	—	—	
Saturation voltage	Collector-emitter	V _{CE} (sat)	I _C = 1 A, I _B = 1 mA	—	—	1.5	V
	Base-emitter	V _{BE} (sat)	I _C = 1 A, I _B = 1 mA	—	—	2.0	
Transition frequency		f _T	V _{CE} = 2 V, I _C = 0.5 A	—	100	—	MHz
Collector output capacitance		C _{ob}	V _{CB} = 10 V, I _E = 0 A, f = 1 MHz	—	20	—	pF
Switching time	Turn-on time	t _{on}	 I _{B1} = -I _{B2} = 1 mA, duty cycle ≤ 1%	—	0.4	—	μs
	Storage time	t _{stg}		—	4.0	—	
	Fall time	t _f		—	0.6	—	

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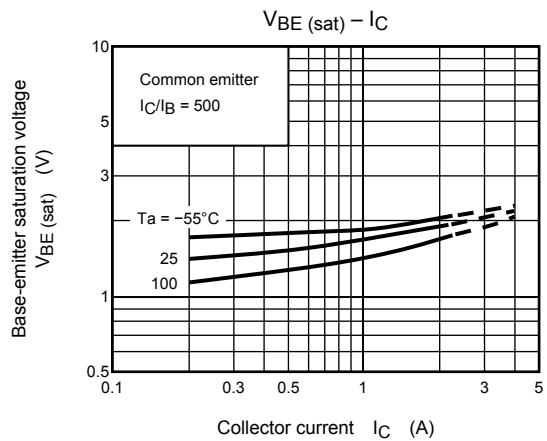
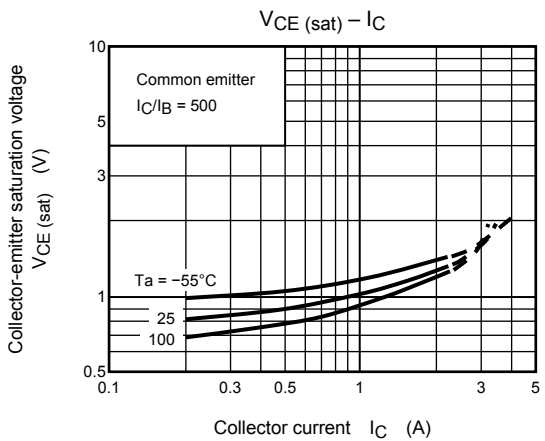
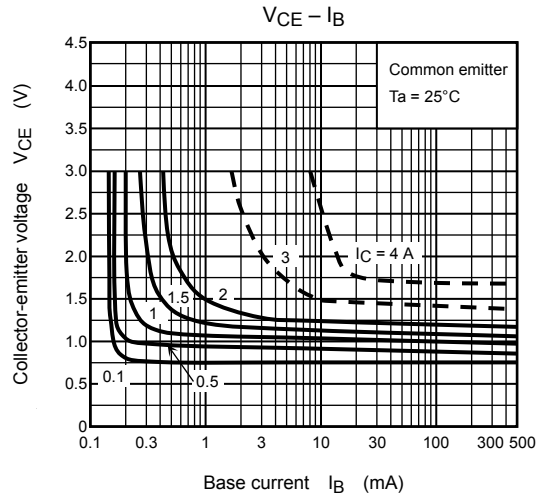
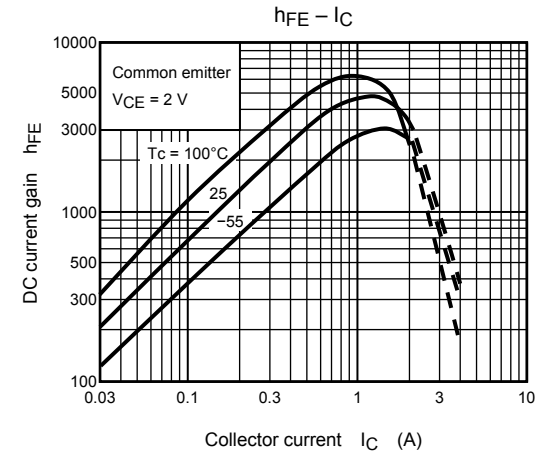
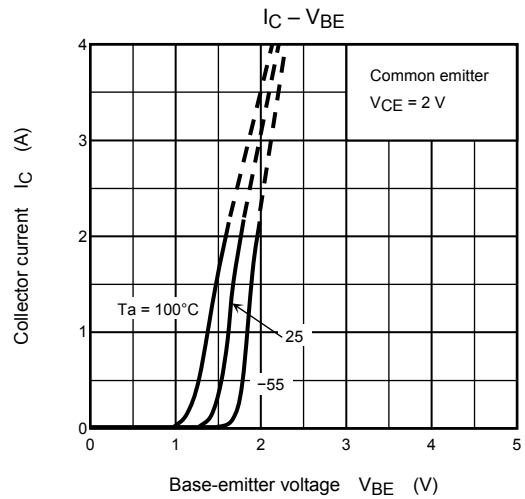
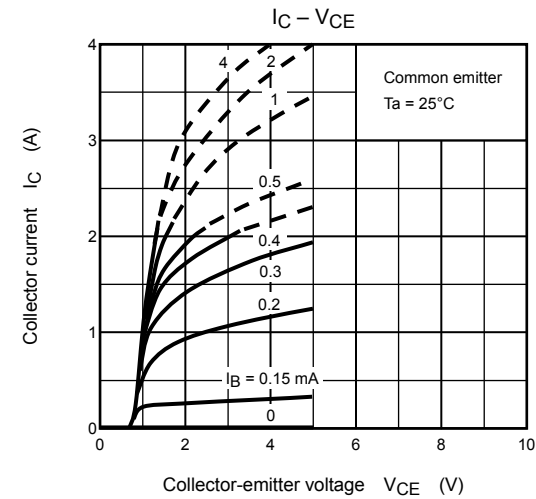
Emitter-Collector Diode Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Maximum forward current	I_{FM}	—	—	—	2	A
Surge current	I_{FSM}	$t = 1 \text{ s, 1 shot}$	—	—	4	A
Forward voltage	V_F	$I_F = 0.5 \text{ A, } I_B = 0 \text{ A}$	—	—	2.0	V
Reverse recovery time	t_{rr}	$I_F = 2 \text{ A, } V_{BE} = -3 \text{ V, } dI_F/dt = -50 \text{ A}/\mu\text{s}$	—	1.0	—	μs
Reverse recovery charge	Q_{rr}		—	5	—	μC

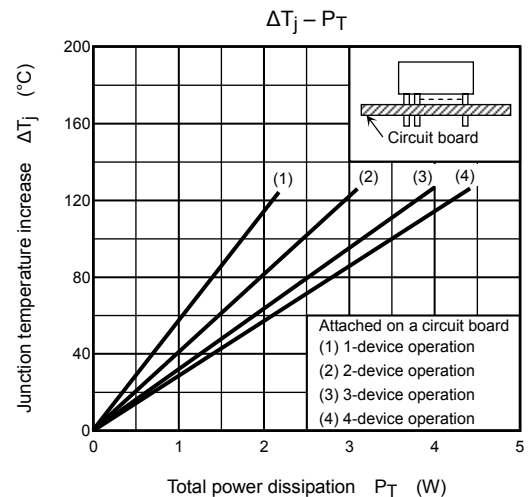
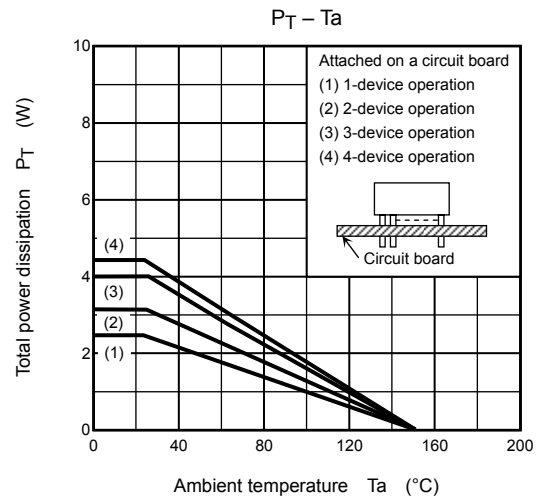
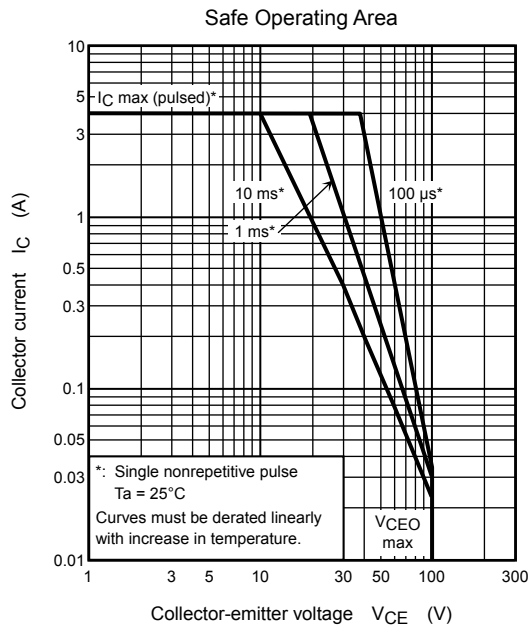
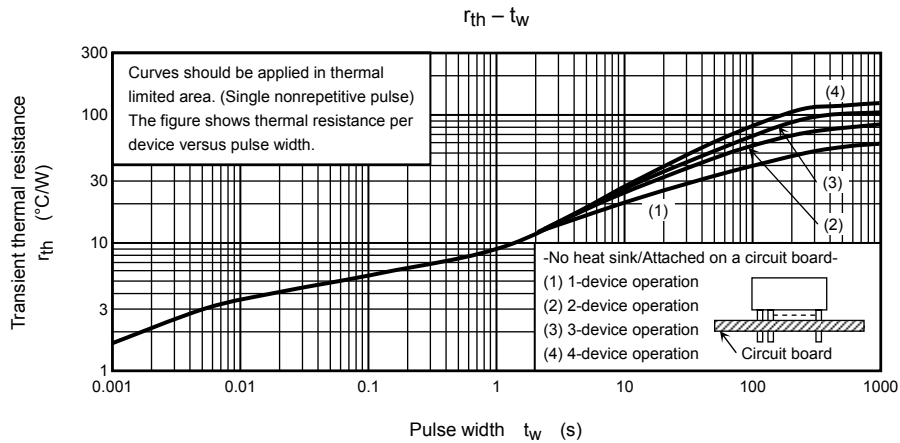
Flyback-Diode Rating and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Maximum forward current	I_{FM}	—	—	—	2	A
Reverse current	I_R	$V_R = 120 \text{ V}$	—	—	0.4	μA
Reverse voltage	V_R	$I_R = 100 \mu\text{A}$	120	—	—	V
Forward voltage	V_F	$I_F = 0.5 \text{ A}$	—	—	1.8	V

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